



# HiPerFRED

$V_{RRM}$	=	600 V
$I_{FAV}$	=	15 A
$t_{rr}$	=	35 ns

High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Single Diode

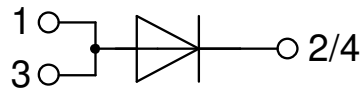
Part number

**DSEP15-06AS**

Marking on Product: DSEP15-06AS



Backside: cathode



**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I<sub>rm</sub>-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>rm</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

**Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

**Package:** TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

**Disclaimer Notice**

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Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					600	V
$V_{RRM}$	max. repetitive reverse blocking voltage					600	V
$I_R$	reverse current, drain current	$V_R = 600\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		100	$\mu\text{A}$
		$V_R = 600\text{ V}$		$T_{VJ} = 150^\circ\text{C}$		0.5	mA
$V_F$	forward voltage drop	$I_F = 15\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		2.04	V
		$I_F = 30\text{ A}$				2.25	V
		$I_F = 15\text{ A}$		$T_{VJ} = 150^\circ\text{C}$		1.35	V
		$I_F = 30\text{ A}$				1.59	V
$I_{FAV}$	average forward current	$T_C = 140^\circ\text{C}$	rectangular	$T_{VJ} = 175^\circ\text{C}$		15	A
$V_{FO}$	threshold voltage			$T_{VJ} = 175^\circ\text{C}$		0.99	V
$r_F$	slope resistance	} for power loss calculation only				15	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					1.6	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.25		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		95	W
$I_{FSM}$	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		110	A
$C_J$	junction capacitance	$V_R = 400\text{ V}$ f = 1 MHz		$T_{VJ} = 25^\circ\text{C}$		12	pF
$I_{RM}$	max. reverse recovery current			$T_{VJ} = 25^\circ\text{C}$		5	A
		} $I_F = 15\text{ A}; V_R = 300\text{ V}$		$T_{VJ} = 100^\circ\text{C}$		7	A
$t_{rr}$	reverse recovery time	} $-di_F/dt = 200\text{ A}/\mu\text{s}$		$T_{VJ} = 25^\circ\text{C}$		35	ns
				$T_{VJ} = 100^\circ\text{C}$		95	ns



Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				1.5		g
$F_C$	mounting force with clip		20		60	N

<sup>1)</sup>  $I_{RMS}$  is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

**Product Marking**



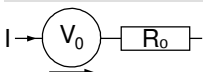
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP15-06AS-TRL	DSEP15-06AS	Tape & Reel	800	513021
Alternative	DSEP15-06AS-TUB	DSEP15-06AS	Tube	50	525177

Similar Part	Package	Voltage class
DSEP15-06BS	TO-263AB (D2Pak) (2)	600
DSEP15-06A	TO-220AC	600
DSEP15-06B	TO-220AC	600

**Equivalent Circuits for Simulation**

*\* on die level*

$T_{VJ} = 175^{\circ}C$



**Fast Diode**

$V_{0\ max}$	threshold voltage	0.99	V
$R_{0\ max}$	slope resistance *	12	mΩ



**Outlines TO-263 (D2Pak)**



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2.54 BSC		0.100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

*All dimensions conform with and/or within JEDEC standard.*



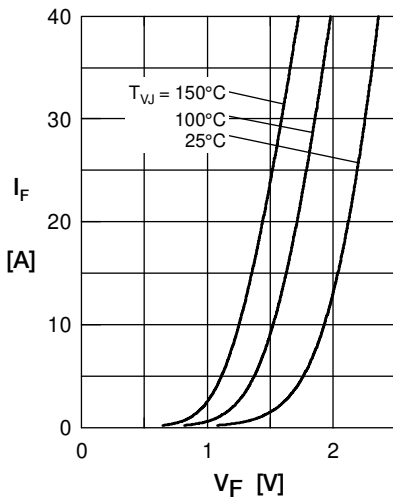
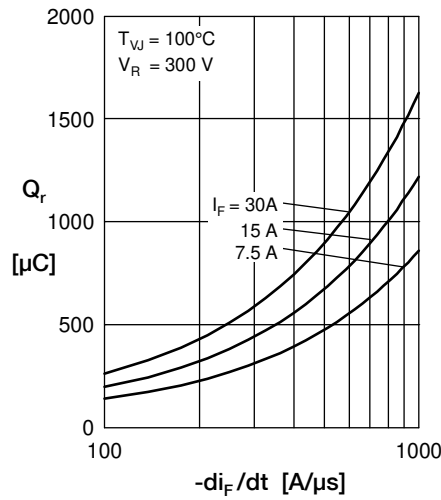
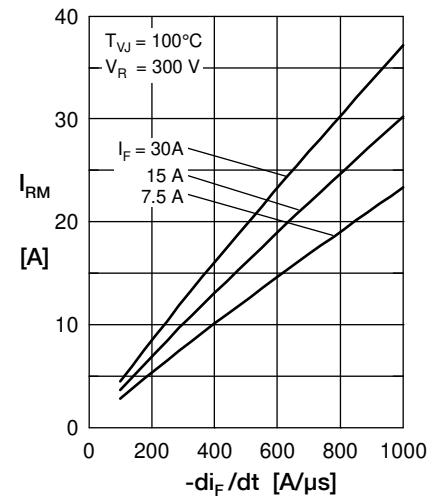
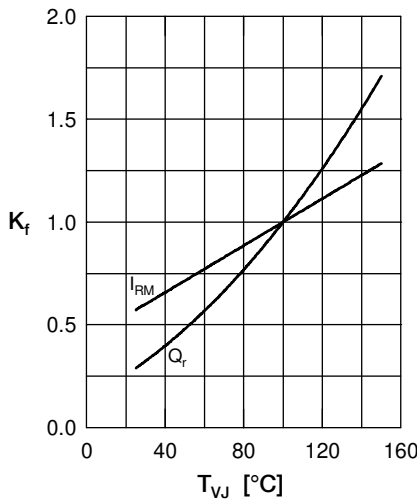
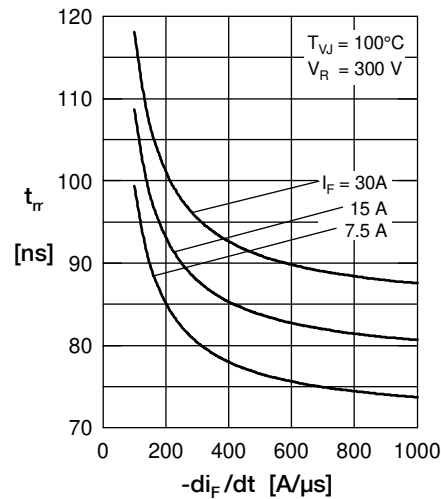
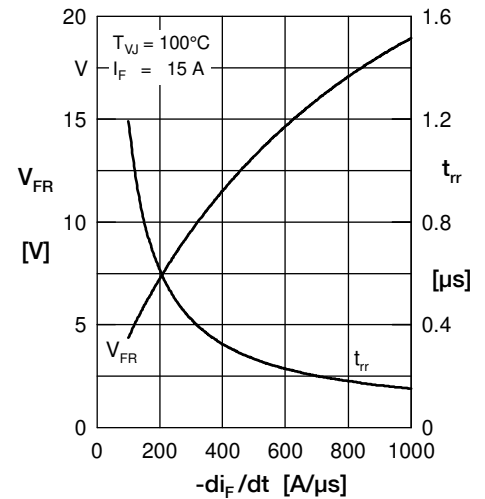
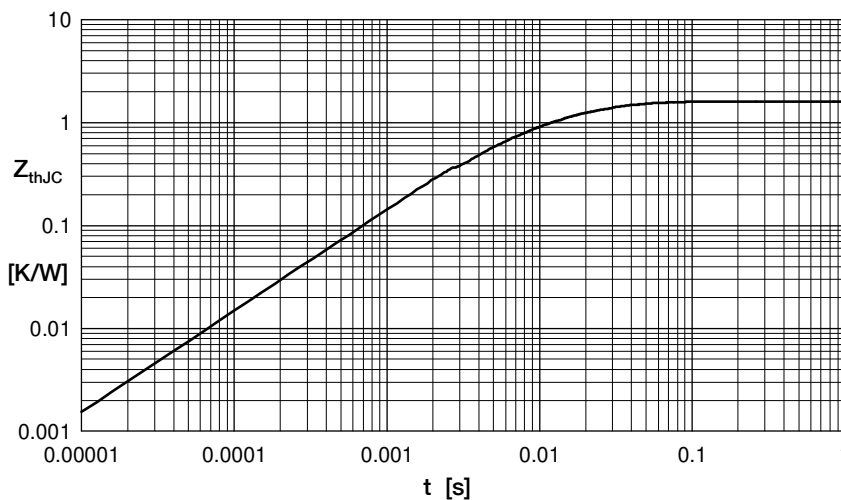
**Fast Diode**

 Fig. 1 Forward current  $I_F$  versus  $V_F$ 

 Fig. 2 Typ. reverse recov. charge  $Q_r$  versus  $-di_F/dt$ 

 Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$ 

 Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ 

 Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$ 

 Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$ 


Fig. 7 Transient thermal impedance junction to case

 Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.908	0.0052
2	0.350	0.0003
3	0.342	0.017